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_	3	sense adj capacitor and cylindrical and silicon adj nitride and silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/04 00:18	
-	846	capacitor and cylindrical and silicon adj nitride and silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/05 15:26	
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-	8	inductive adj capacitor and via and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/05	
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-	9	inductive adj capacitor and cylindrical	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/11 20:39	

-	1	inductive adj capacitor and amorphous	USPAT;	2002/08/11
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			EPO; JPO; DERWENT;	
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_	2	inductive adj capacitor and silicon with	USPAT;	2002/08/11
	_	oxide	US-PGPUB;	20:49
			EPO; JPO;	
			DERWENT;	
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-	358		USPAT;	2002/08/11
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			EPO; JPO;	
			DERWENT; IBM TDB	
_	221	plug and sleeve and inductor and	USPAT;	2002/08/11
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		capacitor and cylinarical	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	42		USPĀT;	2002/08/11
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			DERWENT;	
1_	30	plug and sleeve and inductor and storage	IBM_TDB USPAT;	2002/08/11
-	ا عن	adj capacitor	US-PGPUB;	21:27
		adj capacitor	EPO; JPO;	21.21
			DERWENT;	
			IBM TDB	
_	16	plug and sleeve and inductor and storage	USPĀT;	2002/08/11
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			EPO; JPO;	
			DERWENT;	
	2		IBM_TDB USPAT;	2002/08/11
-	2	adj capacitor and silicon	US-PGPUB;	2002/08/11
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			DERWENT;	
			IBM TDB	
-	181	inductor same storage adj capacitor and	USPAT;	2002/08/11
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			EPO; JPO;	
1			DERWENT;	
1_		 inductor same storage adj capacitor and	IBM_TDB USPAT;	2002/08/11
1	"	silicon and cylirical and memory	USPAT; US-PGPUB;	21:31
		SILISSI WING STILISMI WING MOMOLY	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0		USPAT;	2002/08/11
		silicon and cylirical	US-PGPUB;	21:31
			EPO; JPO;	
			DERWENT;	
_	19	inductor same storage adj capacitor and	IBM_TDB USPAT;	2002/08/11
	19	silicon and cylindrical	US-PGPUB;	21:32
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	8	inductor same storage adj capacitor and	USPAT;	2002/08/11
		silicon and cylindrical and dielectric	US-PGPUB;	21:33
			EPO; JPO;	
		·	DERWENT; IBM TDB	
_	0	stern-donald.in.	USPAT;	2002/08/11
		Storm donard. In.	US-PGPUB;	22:01
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	

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-	41	stern-donald-s.in.	USPAT; US-PGPUB; EPO; JPO;	2002/08/11 22:07
			DERWENT; IBM TDB	
-	829	inductor with capacitor with parallel and silicon	USPAT; US-PGPUB; EPO; JPO;	2002/08/11 22:08
	0.5		DERWENT; IBM_TDB	
-	96	inductor with capacitor with parallel and silicon and (cylindrical or sleeve)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:12
_	6	inductor with capacitor with parallel and silicon and (cylindrical or sleeve) and storage adj capacitor	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 20:59
_	0	inductor with capacitor with parallel and silicon and (cylindrical or sleeve) and storage adj capacitor and sensor adj capacitor	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:14
	. 0	inductor with capacitor with parallel and silicon and storage adj capacitor and sensor adj capacitor	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:14
-	4	inductor same capacitor same parallel and silicon and storage adj capacitor and sensor adj capacitor	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:14
-	1	inductor with capacitor with parallel and silicon and (cylindrical or sleeve) and storage adj capacitor and dielectric	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:19
_	0	plug and capacitor and silicon adj nitride and silicon adj oxide and cvd and etch and trap adj material	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 21:08
_	17	plug and capacitor and silicon adj nitride and silicon adj oxide and cvd and etch and trap	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 21:33
_	17	plug and capacitor and silicon adj nitride and silicon adj oxide and cvd and (inductance or inductor) and memory	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 22:11
-	6	capacitor and first with metal and second with silicon and third with silicon adj dioxide and fourth with silicon adj nitride and plug with metal	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 22:18
-	108	capacitor and silicon and silicon adj dioxide and silicon adj nitride and piezoelectric and memory	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 22:24
-	170	capacitor and silicon and silicon adj dioxide and silicon adj nitride and (piezoelectric or ferroelectric same plug) and memory	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/28 22:24

-	70	capacitor and silicon and silicon adj	USPAT;	2002/08/28
		dioxide and silicon adj nitride and	US-PGPUB;	22:29
		((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory	DERWENT;	
			IBM_TDB	1
-	1	,	USPAT;	2002/08/28
		dioxide and silicon adj nitride and	US-PGPUB;	22:26
		((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory and cylind\$6	DERWENT;	
	0	ganagitar and giligan and giligan adi	IBM_TDB USPAT;	2002/08/28
-	j o	capacitor and silicon and silicon adj dioxide and silicon adj nitride and	US-PGPUB;	22:27
		((piezoelectric or ferroelectric) same	EPO; JPO;	22:21
ļ		plug) and memory and cylindrical	DERWENT;	
1		prag, and memory and cylindrical	IBM TDB	
_	1	capacitor and silicon and silicon adj	USPAT;	2002/08/28
	_	dioxide and silicon adj nitride and	US-PGPUB;	22:30
	•	((piezoelectric or ferroelectric) same	EPO; JPO;	22.30
		plug) and memory and (inductor or	DERWENT;	
1		inductance)	IBM TDB	
-	1	1 =	USPAT	2002/08/28
1	·			22:29
-	70	capacitor and silicon and silicon adj	USPAT;	2002/08/28
		dioxide and silicon adj nitride and	US-PGPUB;	22:30
		((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory	DERWENT;	
			IBM_TDB	
-	0	sense adj capacitor and trap adj material	USPAT;	2002/09/03
			US-PGPUB;	17:22
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1,0	capacitor and trap adj material	USPAT;	2002/09/03
			US-PGPUB;	17:25
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2733		USPAT;	2002/09/03
		dielectric	US-PGPUB;	17:27
		·	EPO; JPO;	
			DERWENT;	`
	2233	inductor and semiconductor and	IBM_TDB USPAT;	2002/09/03
-	2233	dielectric and capacitor	·	17:27
1		diefectic and cabacitor	US-PGPUB; EPO; JPO;	11.41
			DERWENT;	
			IBM TDB	
_	5	inductor and semiconductor and	USPAT;	2002/09/03
		dielectric and sense adj capacitor	US-PGPUB;	17:31
		and any any any	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	, 386	inductor and semiconductor and	USPAT;	2002/09/03
]	dielectric and core and coil	US-PGPUB;	17:31
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	20	solid adj state same inductor and	USPĀT;	2002/09/03
		semiconductor and dielectric and core and	US-PGPUB;	17:31
		coil	EPO; JPO;	
			DERWENT;	
	_	W.CO.40000W	IBM_TDB	
-	3	"6249039"	USPAT;	2002/09/04
			US-PGPUB;	00:18
			EPO; JPO;	
			DERWENT;	
	1	".62.400.20" px	IBM_TDB	2002/00/04
-	1	"6249039".PN.	USPAT	2002/09/04
1_	1	"6240622".PN.	IICDAM	00:18
-		024U022", PN.	USPAT	2002/09/04
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				0000/00/04
-	1	"6069397".PN.	USPAT	2002/09/04 00:19
-	1	"6054750".PN.	USPAT	2002/09/04
_	1	"6031273".PN.	USPAT	2002/09/04
_	1	"6013939".PN.	USPAT	00:23 2002/09/04
_	1	"5956073".PN.	USPAT	00:24 2002/09/04
15	1		USPAT	00:24 2004/09/30
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11	1		USPAT	23:50 2004/09/30 23:50
10	5	"6486529" ·	USPAT;	2004/09/30
			US-PGPUB; EPO; JPO;	23:49
			DERWENT; IBM TDB	
9	8	(("6,346,741") or ("6,054,750") or	USPAT;	2004/09/30
		("6,249,039") or ("6,380,578")).PN.	US-PGPUB; EPO; JPO;	23:49
			DERWENT;	
8	5	((257/531).CCLS.) and ((257/532).CCLS.)	IBM_TDB USPAT;	2004/09/30
ľ	,	and cylinder	US-PGPUB;	23:47
		-	EPO; JPO;	
			DERWENT; IBM TDB	
7	1	((257/531).CCLS.) and ((257/532).CCLS.)	USPĀT;	2004/09/30
		and cup	US-PGPUB; EPO; JPO;	23:26
	,		DERWENT;	
6	87	((257/531).CCLS.) and ((257/532).CCLS.)	IBM_TDB USPAT;	2004/09/30
		((237,031,.0015.) and ((237,032).0015.)	US-PGPUB;	23:25
			EPO; JPO; DERWENT;	
			IBM_TDB	
5	260	(257/534).CCLS.	USPAT; US-PGPUB;	2004/09/30 23:24
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			DERWENT; IBM TDB	
4	1657	(257/532).CCLS.	USPĀT;	2004/09/30
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			DERWENT;	
3	545	(257/531).CCLS.	IBM_TDB USPAT;	2004/09/30
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			EPO; JPO;	
			DERWENT; IBM_TDB	
2 .	375	(257/528).CCLS.	USPĀT; US-PGPUB;	2004/09/30 23:23
			EPO; JPO;	23.23
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1	688	257/528	IBM_TDB USPAT;	2004/09/30
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			IBM_TDB	- 1 - 11-11